	ed States Patent	Y AND TRADEMARK OFFICE	UNITED STATES DEPARTA United States Patent and T Address: COMMISSIONER FOR F P.O. Box 1450 Alexandra, Virginia 22313-14 www.uspto.gov	rademark Office PATENTS
- APPLICATION NO	FILING DATE_	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/934,334	08/21/2001	Paul R. Berger	3531-0103P	8252
2292 7590 06/12/2003 BIRCH STEWART KOLASCH & BIRCH PO BOX 747 FALLS CHURCH, VA 22040-0747			- EXAM	INER
			KANG, DONGHEE	
			ART UNIT	PAPER NUMBER
			2811	
			DATE MAILED: 06/12/2003	3

Please find below and/or attached an Office communication concerning this application or proceeding.

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Office Action Summary The MAILING DATE of this communication an Period for Reply	09/934,334 Examiner Donghee Kang	BERGER ET AL.
The MAILING DATE of this communication a		Art Unit
	Donghoo Kong	
	Dunghee Kang	2811
	ppears on the cover sheet w	vith the correspondence address
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above, is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory perior - Failure to reply within the set or extended period for reply will, by statu - Any reply received by the Office later than three months after the maili earned patent term adjustment. See 37 CFR 1.704(b). Status	I. 1.136(a). In no event, however, may a eppy within the statutory minimum of thind d will apply and will expire SIX (6) MO ute, cause the application to become A	a reply be timely filed inty (30) days will be considered timely. NTHS from the mailing date of this communication. ABANDONED (35 U.S.C. § 133).
1) Responsive to communication(s) filed on 21	<u> August 2001</u> .	
2a) This action is FINAL . 2b)⊠ T	This action is non-final.	
3) Since this application is in condition for allow closed in accordance with the practice unde Disposition of Claims		
4) Claim(s) <u>54-85</u> is/are pending in the applicat	tion.	
4a) Of the above claim(s) is/are withdr	awn from consideration.	
5) Claim(s) is/are allowed.		
6)⊠ Claim(s) <u>54-85</u> is/are rejected.		
7) Claim(s) is/are objected to.		×
8) Claim(s) are subject to restriction and	/or election requirement.	
Application Papers		
9) The specification is objected to by the Examir	ner.	
10) The drawing(s) filed on is/are: a) acc	cepted or b) objected to by	the Examiner.
Applicant may not request that any objection to	the drawing(s) be held in abe	yance. See 37 CFR 1.85(a).
11) The proposed drawing correction filed on	is: a) ☐ approved b) ☐	disapproved by the Examiner.
If approved, corrected drawings are required in I	reply to this Office action.	
12) The oath or declaration is objected to by the E	Examiner.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for forei	ign priority under 35 U.S.C	. § 119(a)-(d) or (f).
a) All b) Some * c) None of:		
1. Certified copies of the priority docume	ents have been received.	
2. Certified copies of the priority docume	ents have been received in	Application No
3. Copies of the certified copies of the pr application from the International E * See the attached detailed Office action for a list	Bureau (PCT Rule 17.2(a))).
14) Acknowledgment is made of a claim for dome		
a) ☐ The translation of the foreign language p 15)⊠ Acknowledgment is made of a claim for dome	provisional application has	been received.
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Attachment(s)		

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DETAILED ACTION

Priority

1. This application appears to be a division of Application No. 09/565,455, filed on May 5, 2000. A later application for a distinct or independent invention, carved out of a pending application and disclosing and claiming only subject matter disclosed in an earlier or parent application is known as a divisional application or "division." The divisional application should set forth only that portion of the earlier disclosure which is germane to the invention as claimed in the divisional application.

Claim Objections

2. Claim 57 is objected to because of the following informalities: the phrase " a secondt quantum well is formed adjacent to, but not necessarily in direct contact with, the bottom injector layer and the tunnel barrier" is misdescriptive. The bottom injector should be the top injector. Appropriate correction is required.

Claim Rejections - 35 USC § 112

3. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

4. Claims **54-73 & 83-85** are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Regarding claims **54-57**, the phrase "a top injector adjacent to, but not necessary in direct contact with, the bottom injector" is unclear since no figure show the top injector

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is in direct contact with the bottom injector. Examiner suggests deleting "but not necessary in direct contact with".

Regarding claim **56**, the phrase "a quantum well is formed adjacent to, but not necessarily in direct contact with, the bottom injector layer and the tunnel barrier" is unclear since figures show that a quantum well is formed in direct contact with the bottom injector layer but not the tunnel barrier.

Regarding claim **57**, the phrase " a first quantum well is formed adjacent to, but not necessarily in direct contact with, the bottom injector layer and the tunnel barrier" and " a second quantum well is formed adjacent to, but not necessarily in direct contact with, the top injector layer and the tunnel barrier" are unclear since figures show that a first and second quantum wells are formed in direct contact with the bottom and top injector layers but not the tunnel barrier.

Regarding claims **54 -57**, the phrase "the bottom injector and top injector layers forming a p-n junction" is unclear how to form the p-n junction between the bottom injector and top injector layers because the top injector is separated by an offset from the bottom injector.

Regarding claim **83**, the phrase "at reduced substrate temperature" is vague and indefinite since what is the reduced substrate temperature does not provided.

Claims 58-73 & 84-85 are rejected since each includes the limitations of independent claims 54-57 & 83.

Claim Rejections - 35 USC § 102

form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

6. Claims **74 & 83-85** are rejected under 35 U.S.C. 102(b) as being anticipated by

Gennser et al. (J.Vac.Sci.Technol.b 8 (2), 1990, pp210).

Regarding claim **74**, Gennser et al. teach a method of fabricating a tunnel diode

by heat treating, during growth of the layers in the tunnel diode (see part II. Experiment

and discussion).

Regarding claims 83-85, Gennser et al. teach a method of fabricating an tunnel

diode by growthing at least quantum well epitaxially at temperature 390 °C.

Claim Rejections - 35 USC § 103

7. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all

obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

8. Claims **75-82** are rejected under 35 U.S.C. 103(a) as being unpatentable over

Gennser et al. (J.Vac.Sci.Technol.b 8 (2), 1990, pp210) in view of Larsen et al.

(Appl.Phys.Lett. 68 (19), 1996).

Gennser et al. do not expressly teach heat treatment using an inert or reducing

atmosphere or moreover a reduction in ambient gas pressure with various temperature

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and times. However, Larsen et al. teach heat treatment in a high flow furnace using an argon ambient with the temperature monitored as a function of time in order to obtain a precise temperature-time set. Temperature between 729 and 1028 °C were used for times between 20 min and 24 h. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to select a proper temperature and time in order to obtain a high crystalline quality layers.

Additional Remarks

9. The lack of an art rejection for claims 54-73 with this Office Action is not an indication of allowance subject matter (i.e, even though the claims 54-73 are rewritten or amended to overcome the rejection under 35 U.S.C 112 as discussed above). The disclosure/claimed language is such that it is impractical to conduct a reasonable search of the prior art by the examiner.

Conclusion

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 703-305-9147. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 703-308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Donghee lang

Donghee Kang Examiner Art Unit 2811

dhk June 9, 2003